

Sintering and electrical characteristics of In₂O₃-based targets doped with multiple components for solar cells

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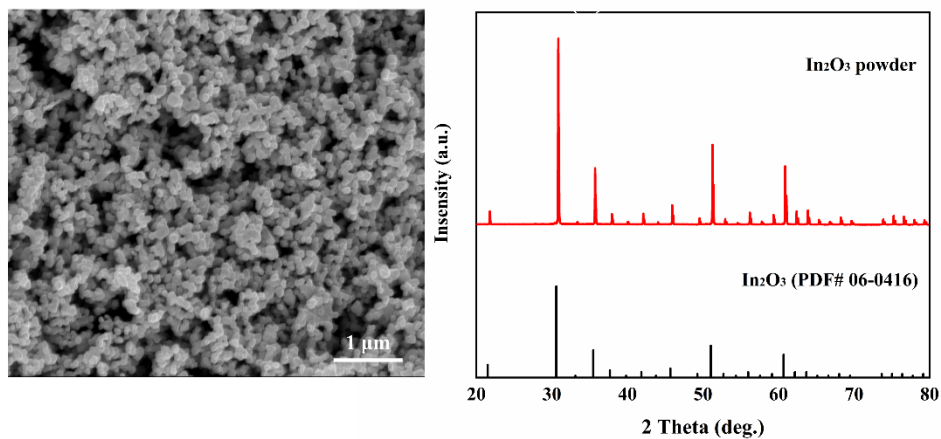


Fig. S1 (Color online) (a) microstructure and (b) XRD patterns of In_2O_3 powders

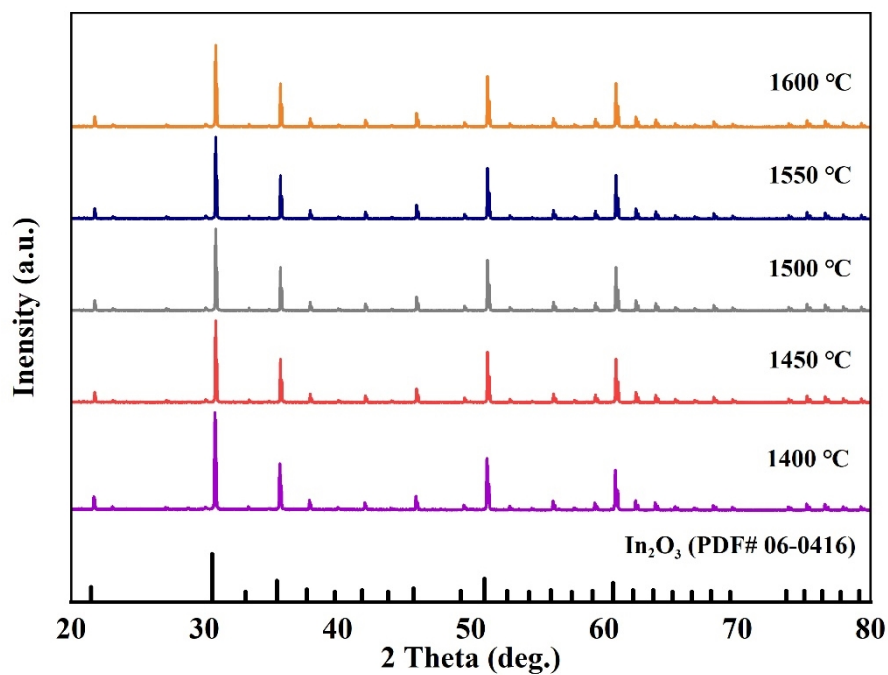


Fig. S2 (Color online) XRD patterns of the ICTO targets sintered at different temperatures for 6 h

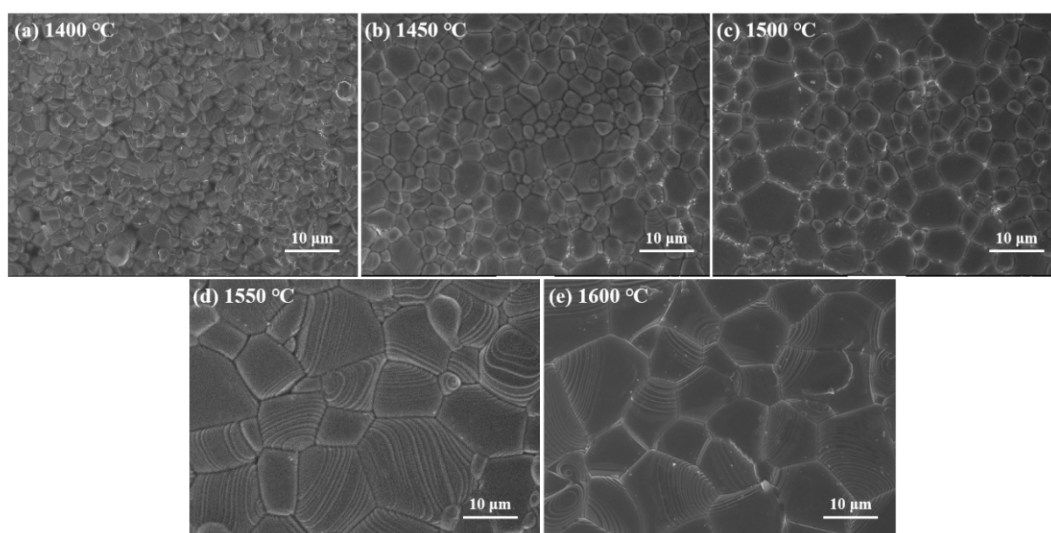


Fig. S3 Surface morphologies of the ICTO targets sintered at different temperatures for 6 h

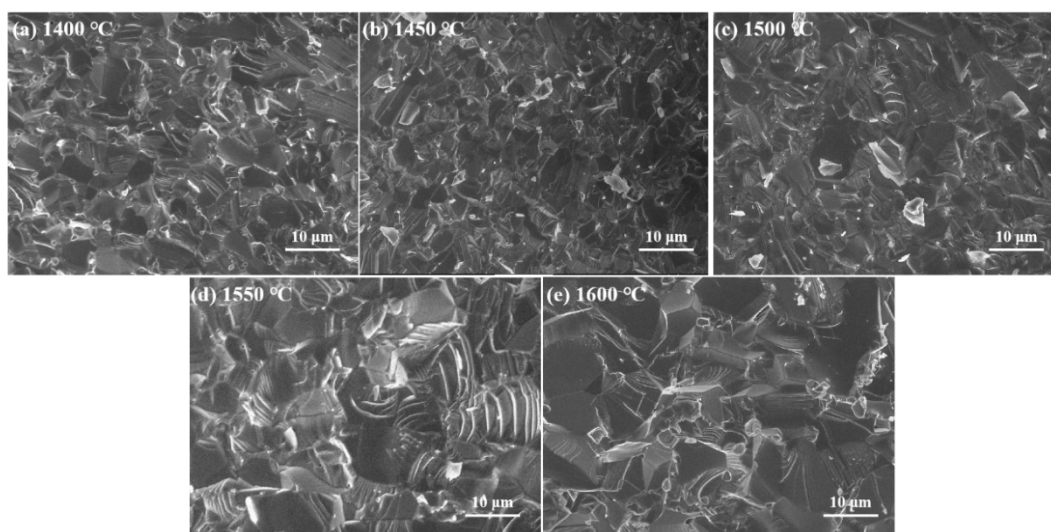


Fig. S4 Cross-sectional morphologies of the ICTO targets sintered at different temperatures for 6 h

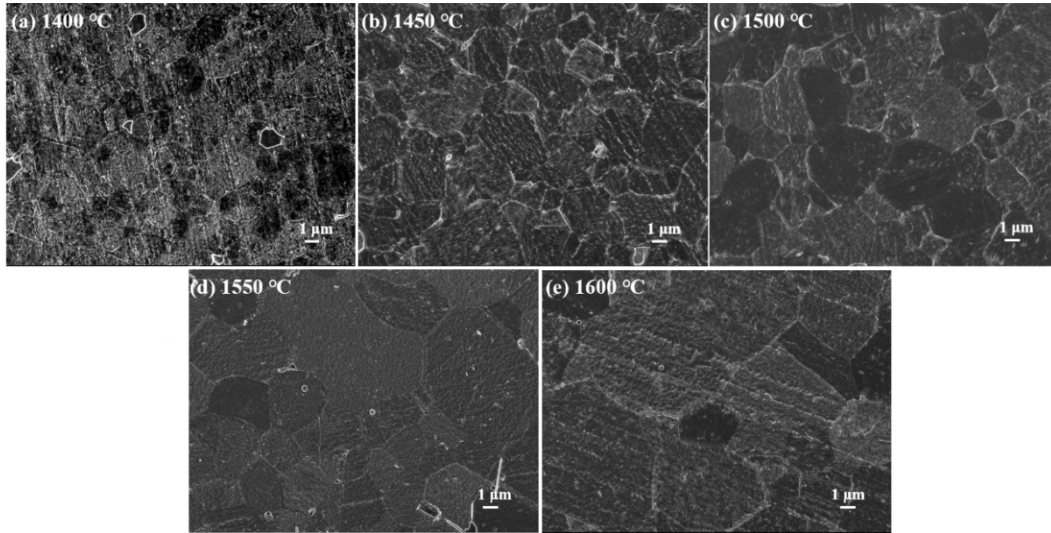


Fig. S5 The polished and etched morphologies of the ICTO targets sintered at different temperatures for 6 h

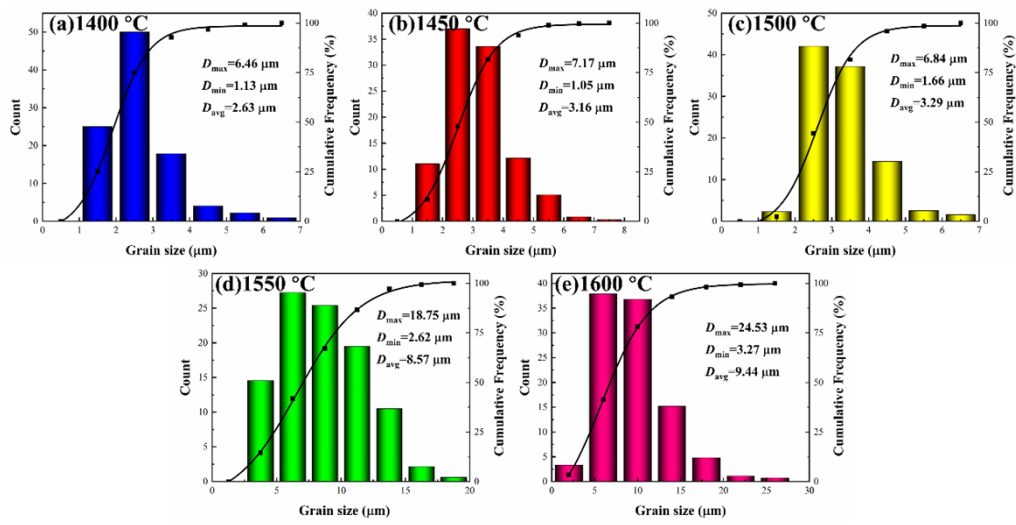


Fig. S6 (Color online) Grain size distribution of the ICTO targets sintered at different temperatures for 6 h